

# 3 V, SILICON MMIC MEDIUM OUTPUT POWER AMPLIFIER FOR MOBILE COMMUNICATIONS

## **UPC8181TB**

#### **FEATURES**

· SUPPLY VOLTAGE:

Vcc = 2.7 to 3.3 V

· CIRCUIT CURRENT:

Icc = 23.0 mA TYP at Vcc = 3.0 V

POWER GAIN:

GP = 19.0 dB TYP at f = 0.9 GHz

GP = 21.0 dB TYP at f = 1.9 GHz

GP = 22.0 dB TYP at f = 2.4 GHz

MEDIUM OUTPUT POWER:

PO(1dB) = +8.0 dBm TYP at f = 0.9 GHz

PO(1dB) = +7.0 dBm TYP at f = 1.9 GHz

PO(1dB) = +7.0 dBm TYP at f = 2.4 GHz

UPPER LIMIT OPERATING FREQUENCY:

fu = 4.0 GHz TYP at 3 dB bandwidth (Standard value)

HIGH-DENSITY SURFACE MOUNTING:

6-pin super minimold package (2.0 x 1.25 x 0.9 mm)

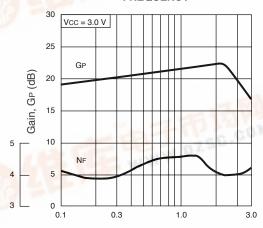
## **DESCRIPTION**

NEC's UPC8181TB is a silicon Monolithic Microwave Integrated Circuit designed as an amplifier for mobile communications. This IC operates at 3 volts. The medium output power is suitable for RF-TX of mobile communication systems.

This IC is manufactured using NEC's 30 GHz f<sub>max</sub> UHS0 (<u>U</u>ltra <u>High Speed</u> process) silicon bipolar process. This process uses direct silicon nitride passivation film and gold electrodes. These materials can protect the chip surface from pollution and prevent corrosion/migration. This IC has excellent performance, uniformity, and reliability.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.

# NOISE FIGURE, POWER GAIN vs. FREQUENCY



Frequency, f (GHz)

#### **APPLICATIONS**

Buffer amplifiers for 1.9 GHz to 2.4 GHz mobile communication systems.

#### **ELECTRICAL CHARACTERISTICS**

 $(TA = 25^{\circ}C, VCC = VOUT = 3.0 \text{ V}, Zs = ZL = 50\Omega)$ 

		UPC8181TB S06				
SYMBOLS	PAF	AMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
Icc	Circuit Current (no sign	nal)	mA	_	23.0	30.0
GP	Power Gain,	f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dB	16.0 18.0 19.0	19.0 21.0 22.0	22.0 24.0 25.0
NF	Noise Figure,	f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dB	_ _ _	4.5 4.5 4.5	6.0 6.0 6.0
fu	Upper Limit Operating I	Frequency, 3 dB down below from gain at f = 0.1 GHz	GHz	_	4.0	_
戈(TS) PDI	Isolation,	f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dB	28.0 27.0 26.5	33.0 32.0 31.5	_ _ _

## **ELECTRICAL CHARACTERISTICS** (cont.)

 $(TA = 25^{\circ}C, VCC = VOUT = 3.0 \text{ V}, Zs = ZL = 50\Omega)$ 

PART NUMBER PACKAGE OUTLINE					UPC8181TB S06		
SYMBOLS	PARA	AMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX	
PO(1dB)	1 dB Gain Compression	Output Level, f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dBm	+5.5 +4.5 +4.5	+8.0 +7.0 +7.0	_ _ _	
Po(SAT)	Saturated Output Powe	r Level, f = 0.9 GHz, PIN = -5 dBm f = 1.9 GHz, PIN = -5 dBm f = 2.4 GHz, PIN = -5 dBm	dBm	- - -	+9.5 +9.0 +9.0	_ _ _	
RLin	Input Return Loss,	f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dB	4.5 7.5 8.0	7.5 10.5 11.0	_ _ _	
RLout	Output Return Loss,	f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dB	6.0 7.0 9.0	9.0 10.0 12.0	- - -	

## **ABSOLUTE MAXIMUM RATINGS<sup>1</sup>**

SYMBOLS	PARAMETERS	UNITS	RATINGS
Vcc	Supply Voltage <sup>2</sup>	V	3.6
Icc	Total Cicuit Current	mA	60
PD	Power Dissipation <sup>3</sup>	mW	270
Та	Operating Ambient Temperature	°C	-40 to +85
Тѕтс	Storage Temperature	°C	-55 to +150
Pin	Input Power <sup>4</sup>	dBm	+10

#### Notes:

- Operation in excess of any one of these conditions may result in permanent damage.
- 2.  $T_A = 25^{\circ}C$ , pins 4 and 6.
- Mounted on a double-sided copper clad 50x50x1.6 mm epoxy glass PWB, TA = +85°C.
- 4. TA = +25 °C

# RECOMMENDED OPERATING CONDITIONS

SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
Vcc	Supply Voltage <sup>1</sup>	V	2.7	3.0	3.3

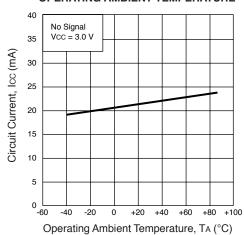
Note:

1. Same voltage applied to pins 4 and 6

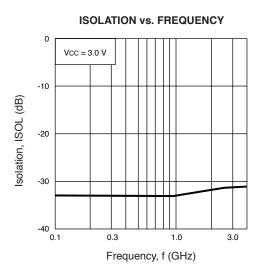
## TYPICAL PERFORMANCE CURVES (Unless otherwise specified, TA = 25°C)

# CIRCUIT CURRENT vs. SUPPLY VOLTAGE 40 35 No Signal 30 25 10 5 0 0 1 2 3 3 4 Supply Voltage, Vcc (V)

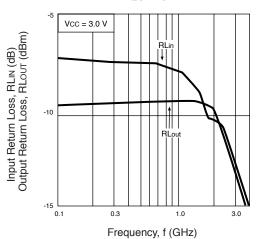
# CIRCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE

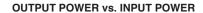


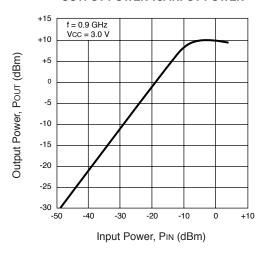
## TYPICAL PERFORMANCE CURVES (Unless otherwise specified, TA = 25°C)



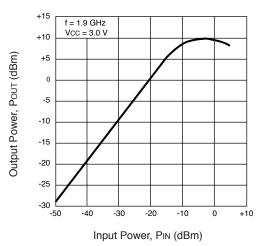
#### INPUT RETURN LOSS, OUTPUT RETURN LOSS vs. **FREQUENCY**



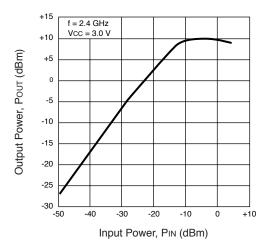




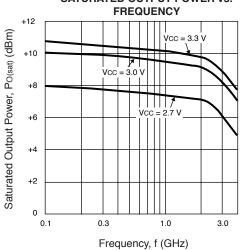
#### **OUTPUT POWER vs. INPUT POWER**



#### **OUTPUT POWER vs. INPUT POWER**

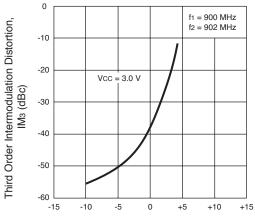


## SATURATED OUTPUT POWER vs.



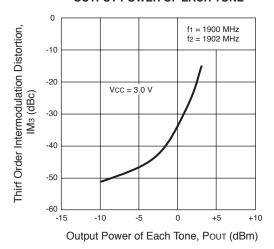
## **TYPICAL PERFORMANCE CURVES** (Unless otherwise specified, $TA = 25^{\circ}C$ )

# THIRD ORDER INTERMODULATION DISTORTION vs. OUTPUT POWER OF EACH TONE

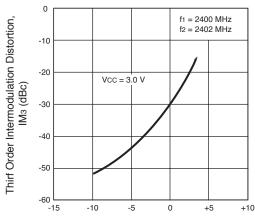


#### Output Power of Each Tone, Pout (dBm)

# THIRD ORDER INTERMODULATION DISTORTION vs. OUTPUT POWER OF EACH TONE

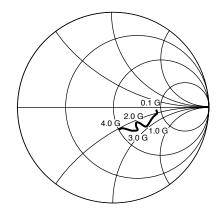


# THIRD ORDER INTERMODULATION DISTORTION vs. OUTPUT POWER OF EACH TONE

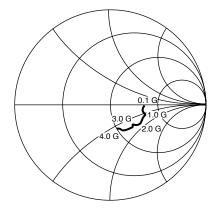


Output Power of Each Tone, Pout (dBm)

## TYPICAL SCATTERING PARAMETERS (TA = 25°C)



Coordinates in Ohms Frequency in GHz Vcc = Vout = 3.0 V, Icc = 23



S11 S22

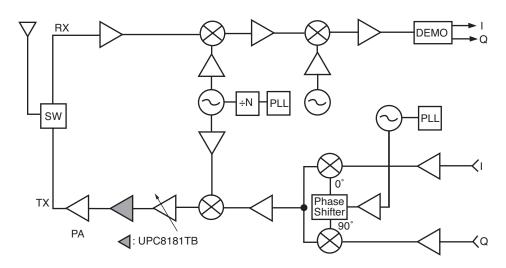
Vcc = Vout = 3.	0 V, Icc = 2	3.0 mA								
FREQUENCY	S	11	,	S <sub>21</sub>	S	S12	S	22		
GHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	<u>K</u>	
0.1	0.452	-2.7	9.078	-2.0	0.020	4.3	0.338	-1.6	1.89	
0.2	0.467	-5.7	9.098	-4.9	0.021	4.2	0.346	-2.1	1.73	
0.3	0.470	-7.5	9.143	-6.9	0.021	8.2	0.344	-1.0	1.72	
0.4	0.460	-9.3	9.237	-10.1	0.021	9.8	0.335	-2.7	1.75	
0.5	0.438	-11.5	9.284	-11.9	0.021	11.4	0.328	-4.8	1.84	
0.6	0.415	-14.7	9.442	-14.6	0.022	8.1	0.337	-7.5	1.73	
0.7	0.397	-18.6	9.670	-17.0	0.022	11.5	0.350	-7.9	1.72	
0.8	0.395	-22.4	9.897	-19.7	0.022	16.3	0.354	-6.8	1.69	
0.9	0.399	-25.6	10.166	-22.7	0.023	14.5	0.342	-6.0	1.56	
1.0	0.404	-28.1	10.496	-26.0	0.022	13.4	0.331	-7.9	1.60	
1.1	0.396	-29.0	10.903	-29.0	0.023	18.0	0.332	-10.8	1.48	
1.2	0.394	-28.5	11.329	-32.8	0.025	16.6	0.353	-13.4	1.33	
1.3	0.385	-28.0	11.895	-37.9	0.025	17.4	0.376	-14.3	1.26	
1.4	0.368	-28.8	12.145	-42.4	0.024	22.0	0.374	-15.0	1.28	
1.5	0.347	-29.5	12.356	-47.6	0.025	24.3	0.361	-16.3	1.28	
1.6	0.335	-30.9	12.670	-51.8	0.026	20.6	0.356	-19.3	1.22	
1.7	0.327	-31.5	12.966	-56.4	0.024	21.4	0.356	-22.0	1.29	
1.8	0.328	-31.2	13.410	-61.4	0.026	23.2	0.366	-23.9	1.17	
1.9	0.327	-29.4	13.722	-66.8	0.027	27.5	0.367	-25.6	1.11	
2.0	0.325	-29.4	14.151	-72.3	0.026	24.6	0.369	-28.5	1.11	
2.1	0.316	-28.5	14.412	-78.1	0.028	26.4	0.363	-31.7	1.05	
2.2	0.295	-29.4	14.747	-84.1	0.027	26.5	0.361	-35.4	1.08	
2.3	0.288	-30.8	15.144	-90.3	0.029	27.5	0.359	-37.1	1.02	
2.4	0.291	-34.1	15.463	-97.4	0.029	27.1	0.346	-39.0	1.01	
2.5	0.303	-38.3	15.264	-104.6	0.029	27.7	0.323	-40.6	1.04	
2.6	0.317	-41.1	15.137	-112.6	0.028	25.5	0.303	-43.1	1.09	
2.7	0.335	-41.3	14.774	-119.8	0.029	25.5	0.294	-43.9	1.07	
2.8	0.349	-41.0	14.176	-127.7	0.031	25.0	0.299	-43.0	1.03	
2.9	0.347	-39.4	13.710	-133.7	0.029	32.9	0.304	-41.3	1.09	
3.0	0.345	-43.2	12.808	-139.8	0.029	24.8	0.317	-44.9	1.15	
3.1	0.341	-45.4	12.313	-146.0	0.031	28.9	0.325	-46.7	1.13	
3.2	0.331	-47.9	11.587	-149.3	0.029	31.6	0.318	-48.7	1.25	
3.3	0.323	-49.8	11.003	-154.5	0.031	31.2	0.315	-52.1	1.27	
3.4	0.311	-52.1	10.638	-157.7	0.031	29.5	0.307	-56.1	1.32	
3.5	0.302	-52.6	10.228	-162.0	0.029	32.5	0.302	-60.0	1.44	
3.6	0.289	-54.9	9.985	-166.5	0.030	31.4	0.303	-63.7	1.47	
3.7	0.266	-56.5	9.543	-170.1	0.030	39.6	0.301	-65.1	1.54	
3.8	0.253	-61.5	9.184	-174.5	0.031	34.1	0.294	-67.5	1.55	
3.9	0.238	-65.6 70.7	8.816	-177.7	0.030	36.2	0.275	-68.8	1.71	
4.0	0.238	-70.7	8.488	178.2	0.032	38.9	0.270	-71.0	1.70	
4.1	0.244	-74.0	8.186	174.3	0.032	37.0	0.266	-75.1	1.75	

## **UPC8181TB**

## PIN FUNCTIONS (Pin Voltage is measured at Vcc = 3.0 V)

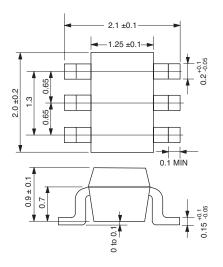
Pin No.	Pin Name	Applied Voltage	Pin Voltage	Description	Equivalent Circuit
1	INPUT	_	0.99	Signal input pin. An internal matching circuit, configured with resistors, enables 50 $\Omega$ connection over a wide band. A multi- feedback circuit is designed to cancel the deviations of hFE and resistance. This pin must be coupled to signal source with capacitor for DC cut.	(a)
2 3 5	GND	0	_	GND pin. This pin should be connected to the system ground with minimuim inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to decrease impedance difference.	1
4	OUTPUT	Voltage as same as Vcc through external inductor	_	Signal output pin. The inductor must be attached between Vcc and output pins to supply current to the internal output transistors.	3 2 5
6	Vcc	2.7 to 3.3	_	Power supply pin, which biases the internal input transistor. This pin should be externally equipped with bypass capacitor to minimize its impedance.	GND GND

## **APPLICATION EXAMPLE** (Digital Cellular Telephone)

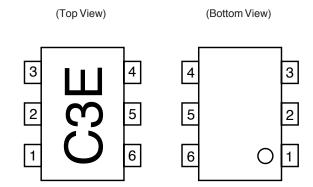


## OUTLINE DIMENSIONS (Units in mm)

#### 6-PIN SUPER MINIMOLD



## **LEAD CONNECTIONS**



- 1. INPUT
- 2. GND
- 3. GND
- 4. OUTPUT
- 5. GND
- 6. Vcc

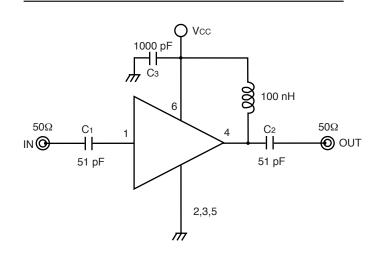
## **ORDERING INFORMATION**

PART NUMBER	PACKAGE	QUANTITY
UPC8181TB-E3-A	6-pin super minimold	3kpcs/Reel

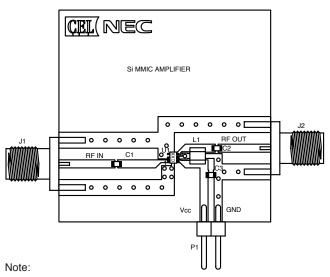
Note: Embossed tape 8 mm wide. Pins 1,2,3 face tape perforation side.

## **TEST CIRCUIT**

Life Support Applications



## **APPLICATION BOARD**



- 1. double sided copper clad GETEK board (H = .028,  $\varepsilon_r$  = 4.2.)
- 2. Back side: GND pattern.
- 3. Solder plated on patterns.
- 4. o O: Through holes.

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CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration in CEL		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

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